# NSN 5961-01-166-7500

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**Inclosure Material:** 

Metal

**Overall Length:** 

0.560 inches

#### **Overall Height:**

0.725 inches

**Overall Width:** 

0.240 inches

#### **Mounting Facility Quantity:**

1

#### Internal Configuration:

Junction contact

#### **Mounting Method:**

Threaded stud

#### Features Provided:

#### Hermetically sealed case

Thread Size:

0.164 inches

#### Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

30.0 breakdown voltage, collector-to-emitter, with specified resistance between base and emitter and 20.0 breakdown voltage,

collector-to-emitter, base open

# **Current Rating Per Characteristic:**

0.50 amperes source cutoff current

#### **Power Rating Per Characteristic:**

8.75 watts small-signal input power, common-collector preset

#### **Transfer Ratio:**

20.0 static forward current transfer ratio, common-emitter and 120.0 static forward current transfer ratio, common-emitter

# Maximum Operating Tempurature Per Measurement Point:

200.0 degrees celsius ambient air

# **Special Features:**

Junction pattern arrangement: npn

# **Thread Series Designator:**

Unc

# Terminal Type And Quantity:

2 ribbon and 1 threaded stud

# Shelf Life:

N/a

# Unit Of Measure:

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### Demilitarization:

No

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